

### **CURRENT MODE PWM CONTROLLER**

### **DESCRIPTION**

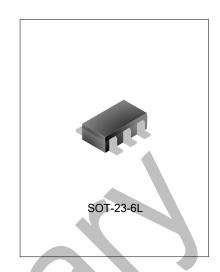
SD4871 is a current mode PWM controller IC for high performance, low standby power offline flyback converter application.

In no load or light load condition, the IC operates in Light Load Mode to reduce switching loss and improve efficiency.

Large startup resistor could be used in the startup circuit to minimize the standby current because of low startup current.

SD4871 offers complete protection functions including cycle-bycycle over current protection, over load protection, over voltage and under voltage protections for V<sub>DD</sub> voltage, etc.

Excellent EMI performance is achieved with frequency shuffling technique and soft switching control at the totem pole gate driver output.



### **FEATURES**

- \* Frequency shuffling to improve EMI performance
- \* Light Load Mode for minimum standby power
- \* External programmable switching frequency
- \* 3µA low startup current
- \* Internal LEB circuit
- \* V<sub>DD</sub> over voltage and under voltage protection
- \* Gate output maximum voltage clamp
- \* Current limiting
- \* Over load protection
- \* SOT-23-6L package

## **APPLICATIONS**

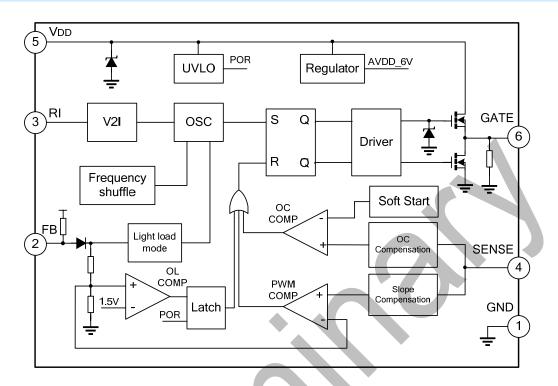
- \* Battery Chargers
- \* Adapters
- \* Set-Top Box Power Supplies

## **ORDERING INFORMATION**

Part No.	Package	Marking	Material	Packing
SD4871TR	SOT-23-6L	4871	Pb free	Tape & Reel



# **BLOCK DIAGRAM**



# **ABSOLUTE MAXIMUM RATINGS**

Characteristics	Symbol	Rating	Unit
Supply Voltage	$V_{DD}$	28	V
Feedback Voltage	$V_{FB}$	-0.3~6	V
SENSE Voltage	V <sub>SENSE</sub>	-0.3~6	V
RI Voltage	$V_{RI}$	-0.3~6	V
Junction Temperature Range	$T_{i}$	-20~150	°C
Lead Temperature	TL	260	°C
Storage Temperature Range T <sub>stg</sub>		-55~160	°C

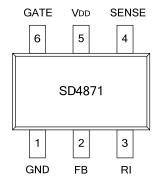
# **ELECTRICAL CHARACTERISTICS** (Unless otherwise specified, T<sub>amb</sub>=25°C)

Characteristics	Symbol	mbol Test Condition		Тур.	Max.	Unit
$V_{DD}$						
Startup Current	I <sub>VDD ST</sub>	$V_{DD}$ =12 V, $R_i$ =100k $\Omega$		3	20	μΑ
Operation Current	I <sub>VDD</sub>	$V_{DD}$ =16V, $V_{FB}$ =3V, $R_{I}$ =100k $\Omega$	· 2 - 2		mA	
Start up Voltage	V <sub>START</sub>		13.3	14.3	15.3	<b>V</b>
Shut down Voltage	V <sub>SHUT</sub>			7.8		V
V <sub>DD</sub> OVP Voltage	V <sub>VDD OVP</sub>			27.5		<b>&gt;</b>
V <sub>DD</sub> Clamp Voltage V <sub>VDD_CLP</sub>		I <sub>VDD</sub> =10mA		28		٧



Characteristics Symbol		Test Condition	Min.	Тур.	Max.	Unit	
Feedback							
PWM Gain	A <sub>VCS</sub>	ΔV <sub>FB</sub> /ΔV <sub>SENSE</sub>		2		V/V	
FB Open Loop Voltage	V <sub>FB_OPEN</sub>		4.5	4.8	5	V	
FB Short Circuit Current	I <sub>FB_SHORT</sub>	FB short connected to ground	0.3	0.35	0.4	mA	
FB OL Threshold Voltage	V <sub>FB OL</sub>			3.8		V	
OL Debounce Time	T <sub>D OL</sub>			35		ms	
FB Input Impedance	Z <sub>FB IN</sub>		18	23	<b>_</b>	kΩ	
Maximum Duty Cycle	D <sub>MAX</sub>	$V_{DD}$ =16V, R <sub>I</sub> =100kΩ $V_{FB}$ =3V, $V_{SENSE}$ =0V		75		%	
Current Sense							
LEB Time	T <sub>LEB</sub>	R <sub>I</sub> =100kΩ		300		ns	
SENSE Input Impedance	Z <sub>SENSE IN</sub>			85		kΩ	
OC Control Delay	T <sub>OC</sub>		/	75		ns	
OC Detection Threshold	V <sub>SENSE OC</sub>	0.7		0.75	8.0	V	
Soft Start							
Soft start time	T <sub>ss</sub>	R <sub>I</sub> =100kΩ	-	4		ms	
Switching Frequency							
Ocsillation Frequency	f <sub>S</sub>	R <sub>I</sub> =100kΩ	60	65	70	kHz	
Frequency Stability With VDD	$\Delta f_{S\_VDD}$	V <sub>DD</sub> =12~28V, R <sub>I</sub> =100kΩ		5		%	
RI External Resistance Range			50	100	150	kΩ	
Light Load Mode Frequency f <sub>S LLM</sub>				22		kHz	
Frequency Shuffling Range	Δf <sub>S_SHUF</sub>	R <sub>I</sub> =100kΩ	-3		3	%	
Gate Driver							
Output Low Level V		V <sub>DD</sub> =16V, I <sub>O</sub> =-20mA			0.8	V	
Output High Level	V <sub>OH</sub>	V <sub>DD</sub> =16V, I <sub>O</sub> =20mA	10			V	
Output Clamp Voltage Level VoH CLAMP				13		V	
Output Rising Time T <sub>R</sub> V		V <sub>DD</sub> =16V, C <sub>L</sub> =1nF		220		ns	
Output Falling Time	T <sub>F</sub>	V <sub>DD</sub> =16V, C <sub>L</sub> =1nF		70		ns	

# **PIN CONFIGURATION**





#### **PIN DESCRIPTIONS**

Pin No.	Pin Name	I/O	Description
1	GND		Ground.
2	FB	I	Feedback input pin.
3	RI	I/O	Oscillator frequency setting pin.  A resistor connected between RI and GND.
4	SENSE	I	Switch current sense input pin.
5	VDD		Power supply pin.
6	GATE	0	Gate driver output pin.

#### **FUNCTION DESCRIPTIONS**

SD4871 is a current mode PWM controller used in applications for offline flyback converter. The description of functions is as follows.

#### **Startup Control**

Startup current of SD4871 is very low so that IC could start up quickly. A large startup resistor can be used in startup circuit to minimize standby power loss yet provides reliable startup in application.

A 2 MΩ, 1/8 W startup resistor is recommended in normal input range.

## **Frequency Shuffling Control**

Frequency shuffling is used in SD4871 to improve EMI performance.

The oscillation frequency is modulated randomly so that the tone energy is spread out. The spread spectrum minimizes the conduction band EMI and the system design can be easier.

The entire application system design can become simpler.

#### **Light Load Mode**

In no load or light load condition, major power loss of total power consumption is from switching loss on the MOSFET transistor switching loss, the core loss of the transformer and the loss on the external snubber circuit, which become the majority in total power loss. The value of those power losses is proportional to switching actions within a fixed period of time. So reducing number of switching actions can reduce the power loss.

SD4871 enters Light Load Mode in no load or light load condition. The gate drive output switches only when output DC voltage drops below a preset level and the switching frequency reduces. Otherwise the gate drive remains at off state.

## **Oscillation Frequency Setting**

The oscillation frequency is determined by resistor connected between RI and GND. The relationship between the value of this resistor and frequency are shown below

 $f_{\text{S}} = \frac{6500}{R_{\text{--}}} (\text{kHz}), \text{ where } R_{\text{RI}} \text{ is the value of external resistor and its unit is } K\Omega.$ 



#### **Current Sense and LEB**

At switching leading edge time, the current spike due to Snubber diode reverse recovery should be chopped off for it will affect the error of PWM comparator. And this is available through internal LEB (Leading Edge Blanking) circuit. So that the external RC filter circuit on SENSE input is no longer required. During the blanking period, the PWM comparator and OC comparator are disabled and MOSFET transistor keeps turn-on state. The minimum on time of MOSFET is LEB time.

#### **Soft Start**

SD4871 features an internal 4ms soft start during startup (when the switching frequency is set to 65kHz).

#### **Gate Driver**

GATE pin is connected to external MOSFET's gate for switch control. Too weak the gate drive ability results in more switch loss of MOSFET while too strong gate drive compromises the EMI performance.

A good tradeoff is achieved through the totem pole gate drive design with appropriate output ability and dead time control.

#### **Protections control**

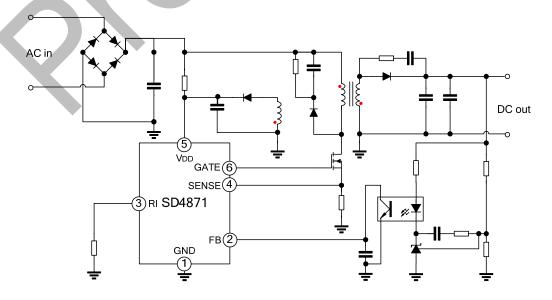
SD4871 offers complete protection functions including cycle-by-cycle over current protection, over load protection, over voltage and under voltage protection for  $V_{DD}$  input voltage, etc.

Constant output power limit over universal input voltage range is achieved with over current protection threshold line voltage compensation to over current protection threshold.

 $V_{DD}$  is supplies by auxiliary winding output of the transformer. It is clamped when  $V_{DD}$  is higher than clamp threshold value. The MOSFET is shut down when  $V_{DD}$  drops below shut-down voltage and IC enters power on startup sequence thereafter.

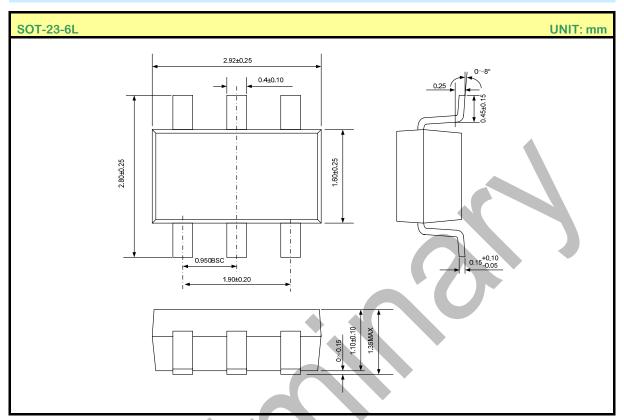
When FB input voltage is higher than over load threshold voltage for more than  $T_{D\_OL}$ , the MOSFET is shut down and  $V_{DD}$  voltage drops. IC restarts when  $V_{DD}$  is lower than shut-down voltage.

# TYPICAL APPLICATION CIRCUIT





## PACKAGE OUTLINEPACKAGE OUTLINE





### **MOS DEVICES OPERATE NOTES:**

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

### Disclaimer:

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